

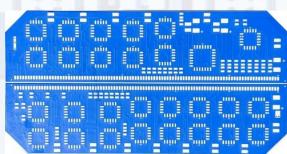
DATA SHEET

At Hybrid Sources, our **thick film experts** provide reliable, high-quality solutions for custom thick film substrate manufacturing. We use the best available technology for **precision screen printing** of conductive, resistive, and insulating pastes resulting in a cost-effective circuit that meets your requirements and specifications.

Standard substrates include **Alumina**, **Beryllium Oxide**, **Aluminum Nitride**, and exotic materials screen printed with various conductive, resistive, and insulating pastes to fabricate single, double-sided, and multilayer circuits. All shapes are possible with intricate patterns cut by laser. Sizes range from 10 mils square to 12 square inches (305mm) while substrate thickness ranges from 5-100 mils (0.005" - 0.100") with 25 mils typical.

Founded in 1985, the company adheres to applicable AS and MIL specs and takes pride in our outstanding on-time delivery record with products Made in the USA.











Substrates

| Material | Descriptions |
|---|--|
| Alumina (Al ₂ O ₃) | 90%, 96%, 99.6%, As fired, Lapped, Polished |
| Aluminum Nitride (AIN) | Lapped |
| Beryllium Oxide (BeO) | As fired, Lapped |
| Exotic Materials | Ferrite, Quartz, Pink Diamonite, Lithium Niobate, Sapphire |

Properties of Common Substrates (tested at 15GHz)

| Properties | Units | Alumina 96% | AIN | BeO |
|-----------------------------------|-------------------|-------------------|-------------------|-------------------|
| Dielectric Constant (1MHz @ RT) | | 9.8 | 8.9 | 6.7 |
| Dielectric loss (1MHz @ RT) | | 0.0001 | 0.0005 | 0.004 |
| Electrical Resistivity | Ohm-cm | >10 ¹⁴ | >10 ¹⁴ | >10 ¹⁴ |
| Thermal conductivity @ T=.040 in. | W/m K | 36 | 170 – 190 | 260 |
| Coefficient of Thermal Expansion | ppm/°C | 8.2 | 4.6 | 8.5 |
| Density | g/cm ³ | 2.89 | 3.3 | 3.85 |
| Bending Strength | mPa | 380 | 290 | 230 |
| Hardness (knoop) | GPa | 14.1 | 11.8 | 9.8 |
| Youngs Modulus | GPa | 372 | 331 | 345 |

Nominal substrate thickness: 10, 15, 20, 25, 40, 60 mils ±10% as-fired. Other thicknesses and tolerances achieved by lapping or pre-sorting.

Intricate patterns



u Company

Size: 10 mil² to 12" dia.

Assembly



Hermetically-sealed



Thick Film Design Guidelines



| Conductor | Symbol | mΩ / □ resistivity | Notes | |
|------------------|--------|-----------------------|--|--|
| Gold | Au | 4 | Wire bondable and low resistance runs | |
| Platinum Gold | PtAu | 40 | Wire bondable, Solderable (no migration) | |
| Silver Palladium | AgPd | 25 | Wire bondable, Solderable (good aged adhesion) | |
| Silver | Ag | 3 | Aluminum wire bondable; prone to oxidation | |

Other conductors available: Platinum (Pt), Palladium Gold (PdAu), Platinum Palladium Gold (PtPdAu), Platinum Silver (PtAg), Platinum Palladium Silver (PtPdAg).

| Conductor Design Guidelines | Notes | |
|--------------------------------------|---|--|
| Line & Space Width | 5 mils (0.005") minimum | |
| Thickness per layer, up to 8 layers | 8-12 microns (gold 6-9 microns) typical | |
| Offset / Pull back from diced edge | 1-5 mils (0.001" to 0.005") ±2 mils | |
| Offset / Pull back from scribed edge | 5 mils (0.005") typical | |
| Offset / Pull back from Dielectric | 3-5 mils (0.003" to 0.005") typical | |
| Alignment | 5 mils (0.005") front to back | |

| Resistors | TCR ppm/°C | Tolerance (no load) | Power dissipation mWatts/mm² |
|---------------|---------------|------------------------|------------------------------|
| <20 ohms | ±100 | 0.50% | 900 |
| 20Ω-100k ohms | ±50 | 0.25% | 120-600 |
| 100k-10M ohms | ±100 | 0.50% | 120 max. |

Laser trimming, solder dipping, 1000 hour load life, stability >0.3% total

Dielectric:

- · Low K dielectric allows up to 12 conductor layers
- High K dielectric allows capacitor formation (0.1 μF/in² max.)



Thick Film Design Guidelines



| Resistors | Description |
|--------------------|--|
| Line & Space Width | 5-10 mils (0.005" to 0.010") minimum |
| Minimum Value | 0.1Ω |
| Maximum Value | 10M Ω typical max., tolerance of ±20%. Can print to 2G Ω . |
| Minimum chip size | 10 mils square (0.010") |
| Minimum Overlap | 3 mils (0.003") |

| Vias (Plated or Solid-filled) | Description | |
|-------------------------------|---|--|
| Diameter | 10 mils (0.010") typical. 5 mil min., 20 mil max. | |
| Minimum metal overlap of pads | 10 mils (0.010") | |

Processing & Assembly

| Processing & Assembly | Description | |
|-----------------------|------------------|--|
| Laser Scribing | Single/Array | |
| Laser Drilling | Vias/Holes | |
| Laser Machining | Per requirement | |
| Diamond Saw Cut | ±2 mils (0.002") | |
| Hermetically-sealed | Per requirement | |

| Wire Bonding | Description | |
|----------------|------------------|--|
| Gold Ball | 1 to 10 mil wire | |
| Gold Wedge | ½ to 3 mil wire | |
| Aluminum Wedge | 1 to 3 mil wire | |
| Ribbon Bonding | 1 to 10 mil wire | |



Standards and Qualifications



| AS & Military Standards | Description |
|---|--|
| AS-9100, Rev. D | Quality Management Systems |
| AS-9003, Rev. A | Inspection and Test Quality Systems |
| MIL-STD-883 | Tests and procedures, microelectronics, High Reliability applications |
| MIL-I-45208 | Quality |
| MIL-M-38510 | General microcircuits |
| MIL-C-45662 | Calibration |
| MIL-Q-9858 | Quality Program |
| Hi Reliability (additional MIL- STD-883 screening) | Stabilization bake, Temperature cycling, Thermal shock, Constant acceleration, Fine and gross leak, Final electrical testing |

| Qualifications | Description |
|-------------------|---|
| RoHS | EU Directive 2015/863 RoHS 3 Annex III 7c-I and 34 Category 9 |
| REACH | Regulation (EC) No 1907/2006 of EU Parliament and Council |
| Conflict Minerals | Dodd-Frank Wall Street Reform & Consumer Protection Act of 2010 |
| NIST SP 800-171 | Certified to Cybersecurity standard for suppliers to the DoD |
| CMMC 2.0 | Compliant with Level 2 Cybersecurity Maturity Model Certification |
| CAGE Code | 07CB1 |
| Made in USA | Manufactured and sourced in USA, unless specified by customer |
| Lockheed Martin | Sole-source qualified supplier for thick film |









Thermal Conductivity Chart



| Material | Chemical | Watts cm • °C |
|--------------------|------------------|------------------|
| Metals: | | |
| Silver | Ag | 4.08 |
| Copper | Cu | 3.94 |
| Gold | Au | 2.96 |
| Aluminum | Al | 2.18 |
| Beryllium | Be | 2.00 |
| Tungsten | W | 1.74 |
| Rhodium | Rh | 1.50 |
| Molybdenum | Мо | 1.46 |
| Brass | 66%Cu, 34% Zn | 1.11 |
| Chromium | Cr | 0.937 |
| Nickel | Ni | 0.920 |
| Platinum | Pt | 0.716 |
| Tin | Sn | 0.666 |
| Tantalum | Та | 0.575 |
| Lead | Pb | 0.353 |
| Titanium | Ti | 0.219 |
| | | |
| PC Boards: | | |
| RT/Duroid® 5880 | | 0.026 |
| G10/FR4® | | 0.027 |
| RT/Duroid® 60 (XX) | | 0.0041- .0048 |
| TMM® (X) | | 0.0068- .0075 |

| Material | Chemical | Watts cm • °C |
|-----------------------|--------------------------------|------------------|
| Insulators: | | |
| Diamond | CVD | 10 – 16 |
| Beryllium Oxide 99.5% | BeO | 2.61 |
| Aluminum Nitride | AIN | 1.70 |
| Sapphire | | 0.46 |
| Alumina Oxide 99.6% | Al ₂ O ₃ | 0.36 |
| Alumina Oxide 96% | Al ₂ O ₃ | 0.26 |
| Alumina Oxide 91% | Al ₂ O ₃ | 0.13 |
| Glass | | 0.015 |
| Mica | | 0.043- 0.0062 |
| Air | | 0.00026 |
| | | |
| Bonding: | | |
| Gold Germanium 88/12 | | 0.8834 |
| Gold Tin 80/20 | | 0.6824 |
| Tin Lead Solder | Sn62 | 0.4921 |
| Indium 100% | | 0.2386 |
| Silver Filled Epoxy | | 0.0156 |
| Ероху | | 0.0099 |

Common Products



| Product | Description | Example | Specifications |
|-------------------|---|---------|---|
| Custom | Single- or multi-layer custom designs built economically up to 8 layers. | | Designed to customer requirements |
| Antennas | Converts voltage from transmitter to radio signal or captures signal for a receiver. | | Built to spec for Frequency, Power, Gain, Return Loss and VSWR. |
| Attenuators | Reduces signal power without distorting waveform; opposite of amplifier. | | Frequency: DC-6 GHz Power: 10-100 Watts Attenuation: 1-20 dB Size: 10 x 20 mils to 0.375" sq. |
| Bonding pads | SMT pad used to connect output pins of an IC or device on a PC board. | | Bondable with Gold or Aluminum wire. Solderable for lead-free or leaded solder materials. |
| Chip Resistors | Passive 2 terminal device that resists flow of current. Available in Tab & Cover, Flange. | | Value: 100mΩ to 10MΩ Power: 30-800W Freq: DC-6GHz Size: 0402 (20x40 mils) to 1" sq |
| Crossovers | SMT bridge replaces the need for a multilayer board or a coaxial jumper. | | Jumper: RF to DC -or- RF to AC Impedance: 50Ω Freq: DC-4GHz, Isolation: 20dB Power Max: 30W |
| Heat Sinks | Passive heat exchanger dissipates heat from a device attached to PC board. | | Thermal conductivity: 30 to 330 W/mK on ALN, Alumina, or BeO |
| Heaters | Heating element assures uniform and directional heat for accurate readings. | | Printed on ceramic substrates in custom shapes and sizes. |





| Product | Description | Picture | Specifications |
|-----------------------------|---|---------|--|
| Sensors | Hall Effect Sensor: detects presence & magnitude of magnetic field. Oxygen Sensor: measures proportion of oxygen (O ₂) in gas or liquid. pH Sensor: measures alkalinity & acidity in water liquid. Pressure Sensor: measures strain or pressure. Proximity Sensor: detects presence of objects as near as 5 mils without physical contact. Temperature Sensor: measures temperature using thermistors. | | Specifications: Built to customer specifications. Substrates: Generally Alumina; all ceramic substrates available. Operating Range: Broad temperature range, typically -55°C to 150 or 200°C. Sensing Distance: Min. 5 mils to detect RPMs by measuring dot on rotating shaft. Output: Voltage or current if needed. |
| Static Transfer Plate | Moves Semiconductor wafers with static electricity | | Peak Voltage: 3,000V |
| Terminations | Resistor grounded at end of transmission line prevents reflected signal from causing distortion. | | Power: 30-800W Freq: DC-8.5GHz Size: 0402 (20x40 mils) to 1" sq Mounting: Chip, Tab & Cover, Flange mount. |
| Thermistors | Thermal Resistor is a component with resistance dependent on temperature. | | Type: NTC or PTC Size: 0402 (20x40 mils) to 1" sq Op. Temperature: -40 to 125°C |

Industries & Applications





Industries

- Aerospace
- Analytical Instruments
- Automotive
- · Automatic Testing Equipment
- · Commercial Airlines
- Consumer
- Defense
- Health and Beauty Appliances
- High Technology
- · Industrial Packaging Equipment
- Medical Diagnostics
- Medical Devices
- Military Aircraft
- Molecular Technology
- Oil & Gas
- Pharmaceutical
- RF and Microwave products
- Satellite and space exploration
- Semiconductor Fabrication
- Sensors
- Submarines
- Telecom
- Test & Measurement
- University & Research Institutions

Applications

- Aegis Radar Electronics
- Attenuators
- Automatic Test Stations
- CERN Large Hadron Collider
- Airbus A320, A350, Boeing 737, 787
- Crossovers, Jumpers
- Diagnostic Analyzers
- · Heat Sinks for PC boards
- Mars Rovers
- Microwave Subsystems (Antennas, Filters, Isolators, Oscillators, Power Amplifiers, Radar, RC Networks)
- F-35 JSF, F-16 Fighting Falcon, F-15 Eagle, F-14 Tomcat
- Molecular blood testing
- Plasma Cleaners
- Resistors
- Semiconductor fabrication equipment
- Sensors (Hall Effect, Oxygen, Pressure, Proximity, pH, Temperature)
- · Virginia-class, Seawolf-class subs
- Terminations
- Thermistors





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